

iXblue solutions for high power lasers based on beam combining technique

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NIR-MPX-LN-0.1-MPX-LN-0.1: a low frequencies phase modulator



- **High input impedance:**

- for efficient RF generator signal transmission transfer to the modulator.
- To avoid thermal effect and signal degradation due to phase drift.

⇒ High impedance modulator and purely capacitive electrodes vanish thermal effect and phase drift. This ensures stable operating performance over a large temperature range.

Application Note: “iXblue: Use of LiNbO_3 modulators at low frequencies”

- **Very low V_π :**

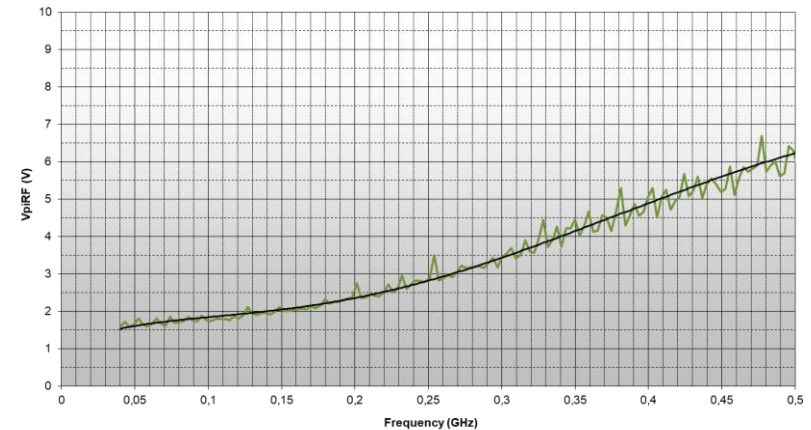
- Modulator V_π is proportional to the Electro-Optical bandwidth
- The (NIR-)MPX-LN-0,1 features a V_π of only 1,5 V @ 50 MHz

⇒ Low V_π at low frequencies minimizes RF power consumption

- **High packaging quality:**

- Telcordia and space qualifications (TRL9 with NASA)

⇒ Packaging and specific mechanical housing for harsh environmental conditions.



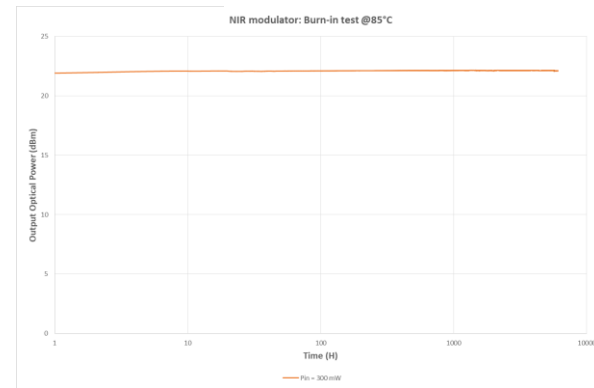
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NIR-MPX-LN-0.1 a low frequencies phase modulator



- **Incomparable optical waveguide and the key optical performances reached:**

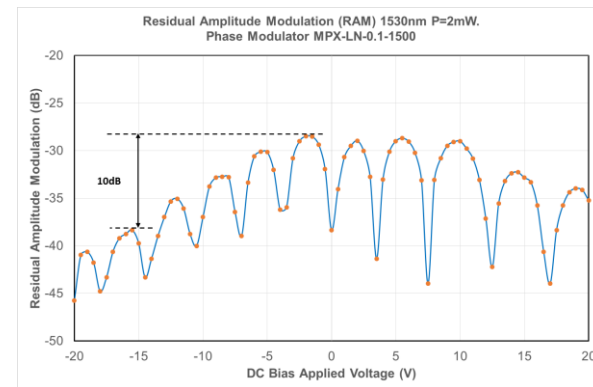
- Annealed Proton Exchange process on a selected LiNbO₃ doped wafer.
- Polarizing waveguide : PER > 20 dB, and > 25 dB with option PER.
- Very low insertion loss : IL < 3 dB. Gaussian distribution with a 2 dB typical mean.
- High optical power handling capability of up to 300 mW.
- High resistance to refractive index effect changes and Pyro-electric effect.
 - ⇒ iXblue offers the best LiNbO₃ phase modulator optical performance.
 - ⇒ High optical performance is stable over the temperature range and over time



Application Note: *"iXblue; Introducing the iXblue NIR-MPX-LN-0.1"*

- **Mitigate the RAM effect:**

- The (NIR-)MPX-LN-0.1 is a DC coupled device: a permanent DC signal can be applied w/o modulator damages
- Applying a constant DC voltage allows to reduce the RAM from typically 30dB to near 40dB (patented technique)
 - ⇒ Residual amplitude modulation can be strongly reduced thanks to a permanent DC voltage



Application Note: *"Residual Amplitude Modulation of optical phase modulators"*

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DR-VE-0.1-MO a RF amplifier to match the (NIR-)MPX-LN-0.1 phase modulator



- **Perfect matching between the modulator and the RF generator:**

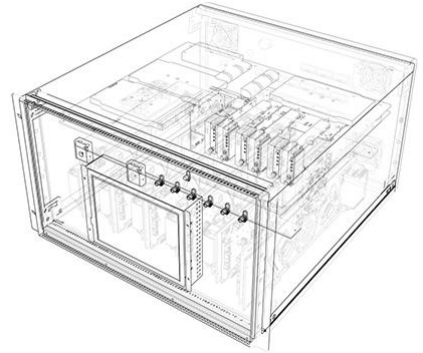
- High impedance for efficient RF signal amplification from the generator to the modulator,
- Adapted bandwidth
- Mechanical matching
- DC coupled amplifier
 - ⇒ Simple and inexpensive, the DR-VE-0.1-MO is a DC-coupled voltage amplifier that operates over a DC to 200 MHz bandwidth.
 - ⇒ Draws very little current.

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Custom component integration designs based on Customer specification: the ModBox

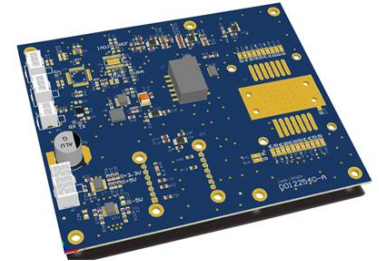
- **Custom Optical Systems & Instruments**

- The ModBox systems are Optical Transmitter solutions based on external LiNbO_3 modulation means.
- iXblue has the inter-disciplinary expertise to integrate simple to complex electro-optical systems and sub-systems.
- In-depth knowledge in Photonics, RF and hyper-frequency, electronics and interfacing.
- ModBox addresses the Telecom, Communication and lasers markets, from 780 nm to 2 500 nm.
- Strong background and High competences in the high energetics and powerful lasers field.
 - ⇒ Who knows better than the EOM manufacturer on how to use their own products ?



- **Turn-key ModBox is a dedicated product for customers needs**

- From prototype base plates to modules, or racks,
- to industrial and reproduceable module or rack solutions.
- Prototype ModBox hardware will be accessible and re-configurable.
- The ModBox system meets the European standards and are compliant with the EMC and optical norms EN61326-1 Ed. 2006 / NF EN 60825-1 & EN 60825-2 Ed.2014.



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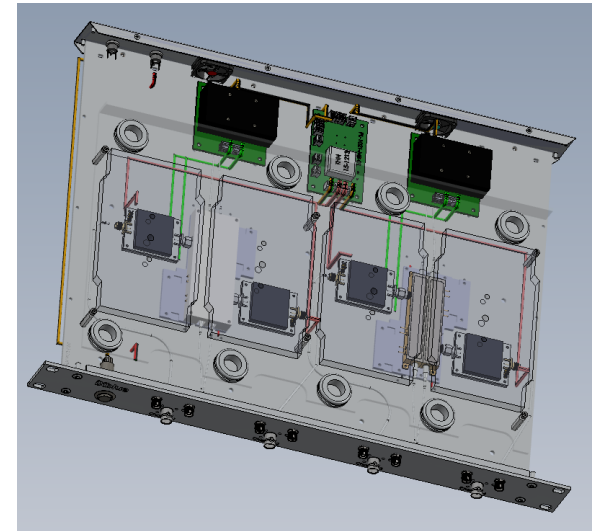
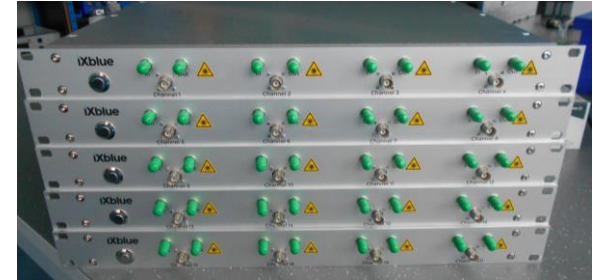
ModBox proposal for NIR-MPX-LN-0.1 and matching components integration

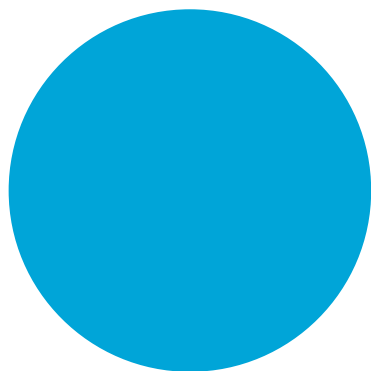
- **The Modbox integration scenarios**

- The rack size depends on the number of components to integrate
- One rack can embed several phase modulator channels, each constituted by:
 - a phase modulator (NIR-)MPX-LN-0.1 optimized for 300 mW CW power handling
 - an optional RF amplifier DR-VE-0.1-MO
 - an optional fix delay line
 - an optional tunable delay line for an adjustable delay up to 600 ps
 - an optional power supply (220 V) otherwise 12 V supply in

- **Example of integration into a rack**

- 8x(NIR-)MPX-LN-0.1 + 8xDR-VE-0.1-MO + 8xTunable Delay Line
- 2U rack with a 495 mm depth
- USB connection and GUI for driver and delay line controls





Annex

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Some formulas



- **Induced electro-optical phase variation**

- Refractive index variation induced by the electro-optical effect when a DC voltage V is applied:

$$\Delta n(V) = \frac{1}{2} n_e^3 r_{33} \Gamma \frac{V}{g}$$

- Relative phase variation:

$$\Delta \varphi(V) = \frac{2\pi}{\lambda} \Delta n(V) L = \frac{2\pi}{\lambda} \frac{1}{2} n_e^3 r_{33} \Gamma \frac{V}{g} = \pi \frac{V}{V_\pi}$$

- Maximum RF phase variation with a sinusoidal peak to peak voltage V at a frequency f :

$$\Delta \varphi(V, f) = \pi \frac{V}{V_\pi(f)}$$

- Exemple: using the maximal range of +/-20V and a $V_\pi=1,5V$, a phase shift of 27π rads can be generated.

- **Equivalent time delay to the phase variation**

$$\Delta t(V) = \frac{\Delta n L}{c} = \frac{\lambda}{2c} \frac{V}{V_\pi}$$